

RF POWER transistor, LdmoST plastic family N-channel enhancement-mode, lateral MOSFETs

Features

- Excellent thermal stability
- Common source configuration
- $P_{OUT} = 25 \text{ W}$ with 14.5dB gain @ 500 MHz / 12.5 V
- New RF plastic package

Description

The device is a common source N-channel, enhancement-mode lateral field-effect RF power transistor. It is designed for high gain, broad band commercial and industrial applications. It operates at 12 V in common source mode at frequencies up to 1 GHz. The device boasts the excellent gain, linearity and reliability of ST's latest LDMOS technology mounted in the first true SMD plastic RF power package, PowerSO-10RF. The device's superior linearity performance makes it an ideal solution for car mobile radio. The PowerSO-10 plastic package, designed to offer high reliability, is the first ST JEDEC approved, high power SMD package. It has been specially optimized for RF needs and offers excellent RF performance and ease of assembly. Mounting recommendations are available in www.st.com/rf/ (look for application note AN1294).

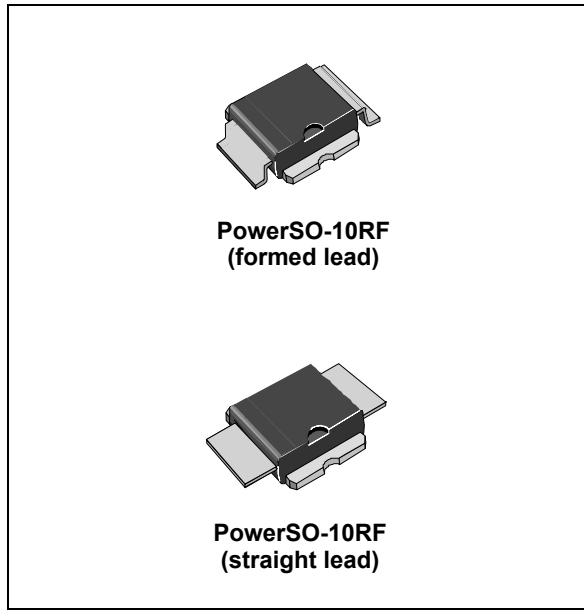


Figure 1. Pin connection

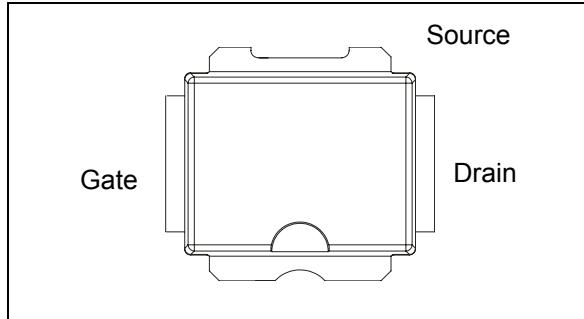


Table 1. Device summary

Order code	Package	Packing
PD55025-E	PowerSO-10RF (formed lead)	Tube
PD55025S-E	PowerSO-10RF (straight lead)	Tube
PD55015TR-E	PowerSO-10RF (formed lead)	Tape and reel
PD55015STR-E	PowerSO-10RF (straight lead)	Tape and reel

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1 Electrical data

1.1 Maximum ratings

Table 2. Absolute maximum ratings ($T_{CASE} = 25^\circ\text{C}$)

Symbol	Parameter	Value	Unit
$V_{(BR)DSS}$	Drain-source voltage	40	V
V_{GS}	Gate-source voltage	± 20	V
I_D	Drain current	7	A
P_{DISS}	Power dissipation (@ $T_C = 70^\circ\text{C}$)	79	W
T_J	Max. operating junction temperature	165	$^\circ\text{C}$
T_{STG}	Storage temperature	-65 to +150	$^\circ\text{C}$

1.2 Thermal data

Table 3. Thermal data

Symbol	Parameter	Value	Unit
R_{thJC}	Junction - case thermal resistance	1.2	$^\circ\text{C}/\text{W}$

3 Impedance

Figure 2. Current conventions

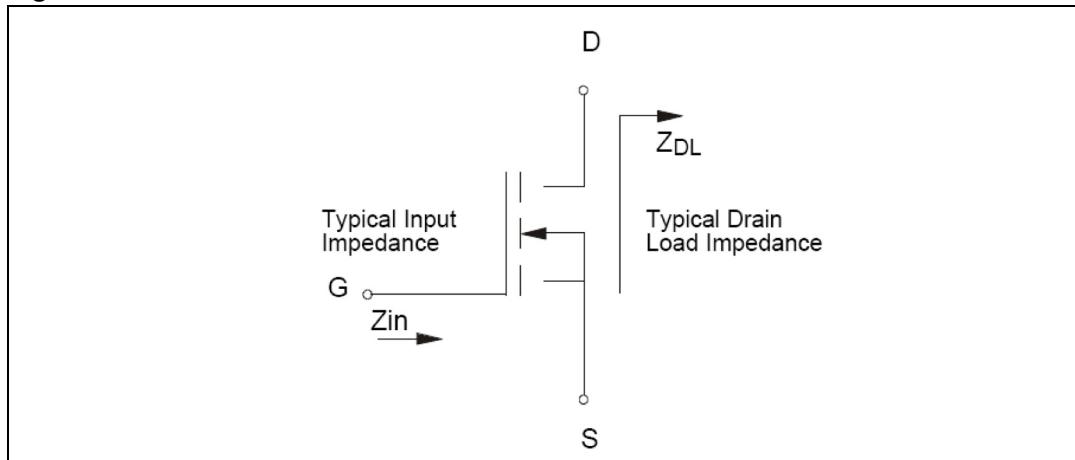


Table 7. Impedance data

Freq. (MHz)	Z _{IN} (Ω)	Z _{DL} (Ω)
175	3.20 - j 4.41	1.56 + j 2.14
480	1.01 - j 1.67	1.06 + j 0.22
500	0.93 - j 1.53	1.12 + j 0.20
520	0.88 - j 1.98	1.07 + j 0.83

4 Typical performance

Figure 3. Capacitance vs supply voltage

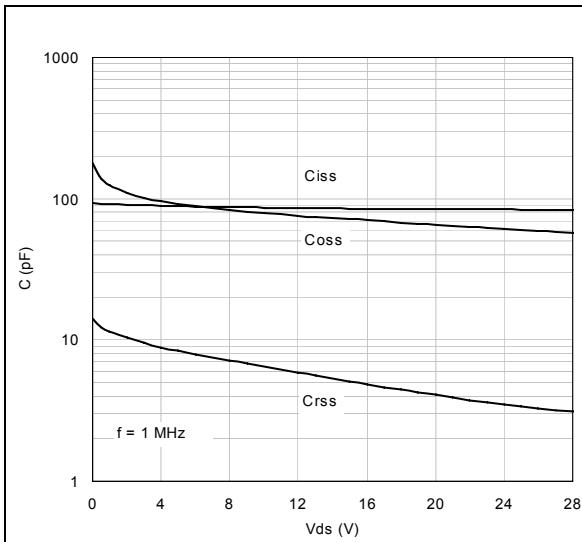


Figure 4. Drain current vs gate source voltage

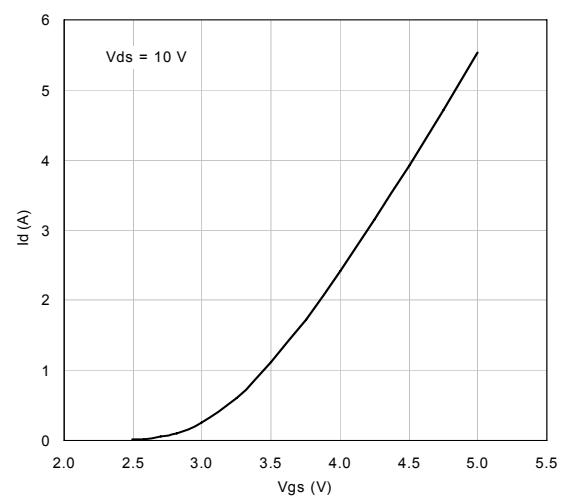


Figure 5. Gate-source voltage vs case temperature

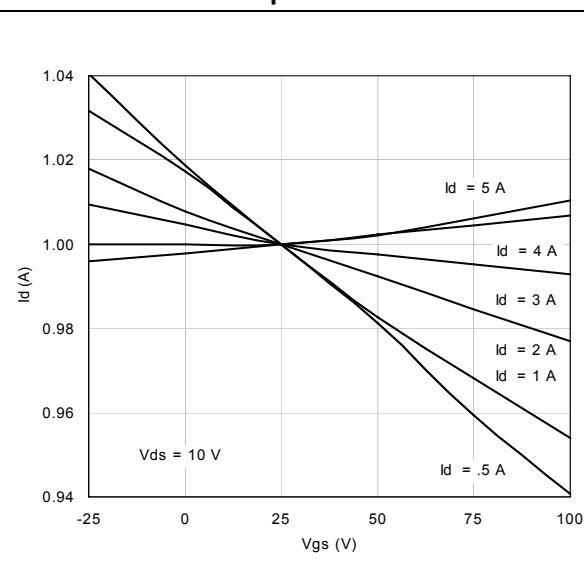


Figure 6. Output power vs input power

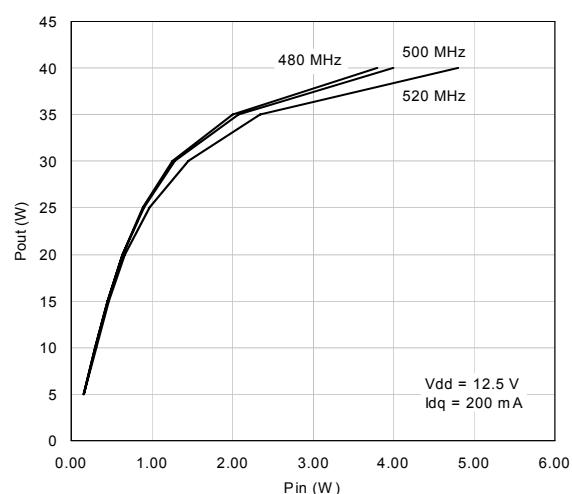


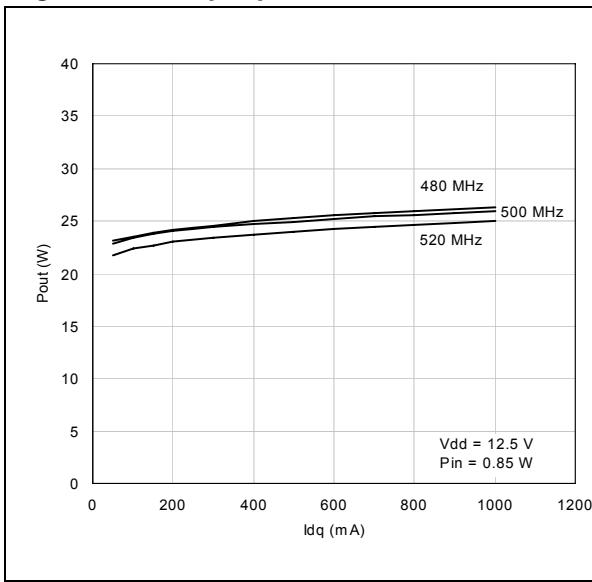
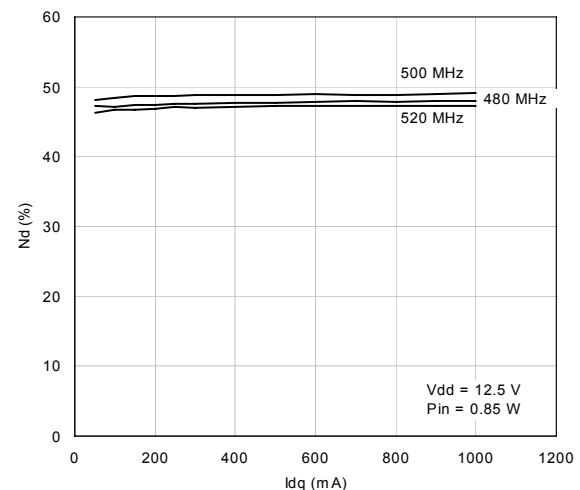
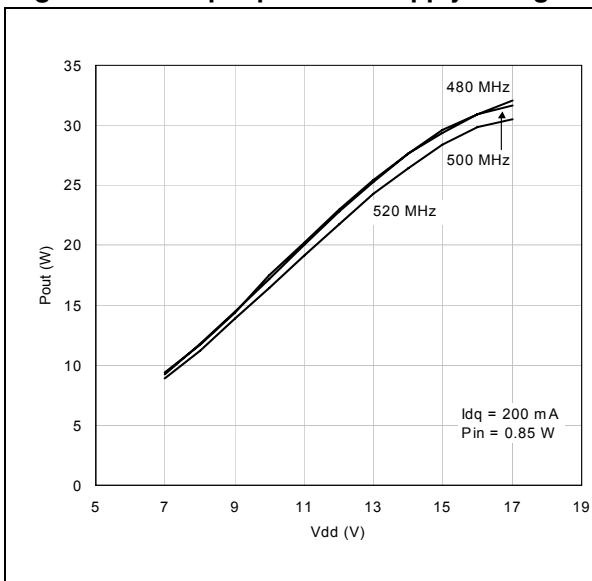
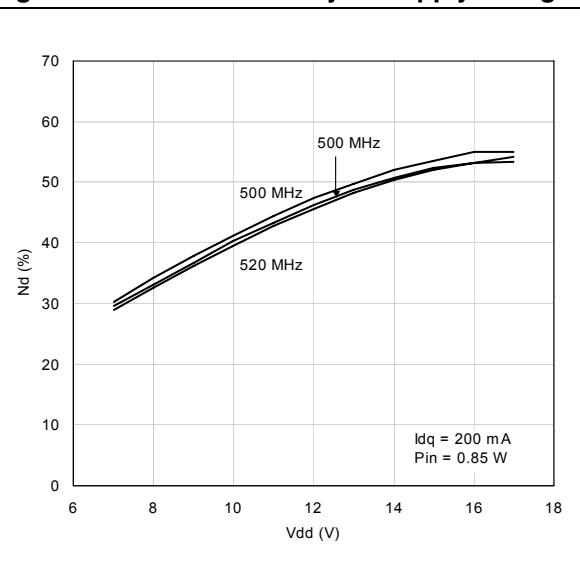
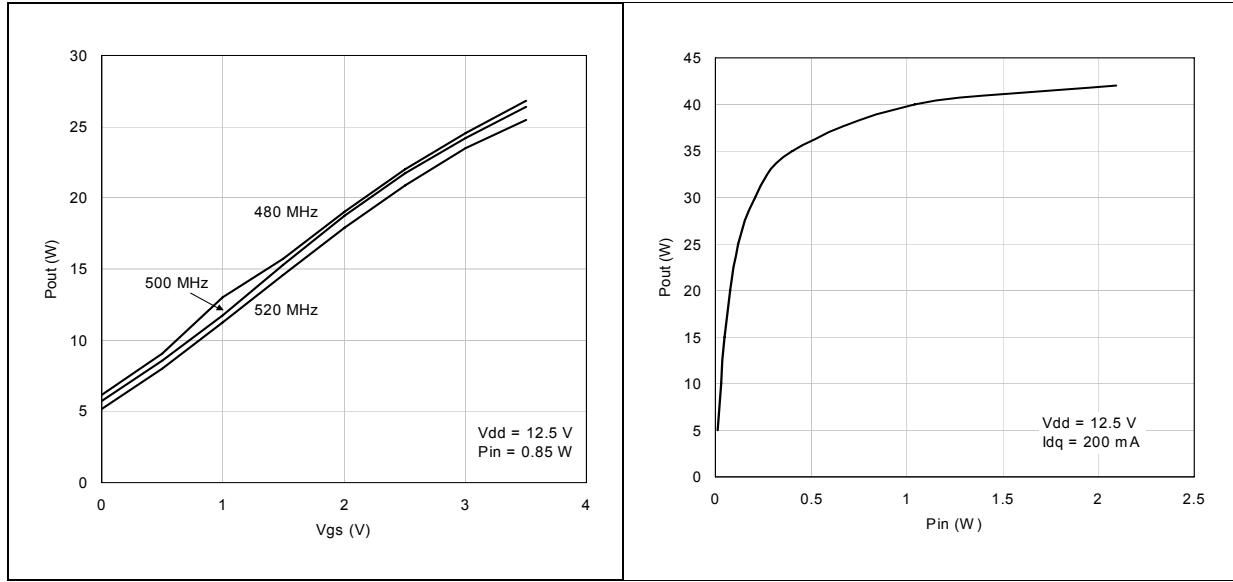
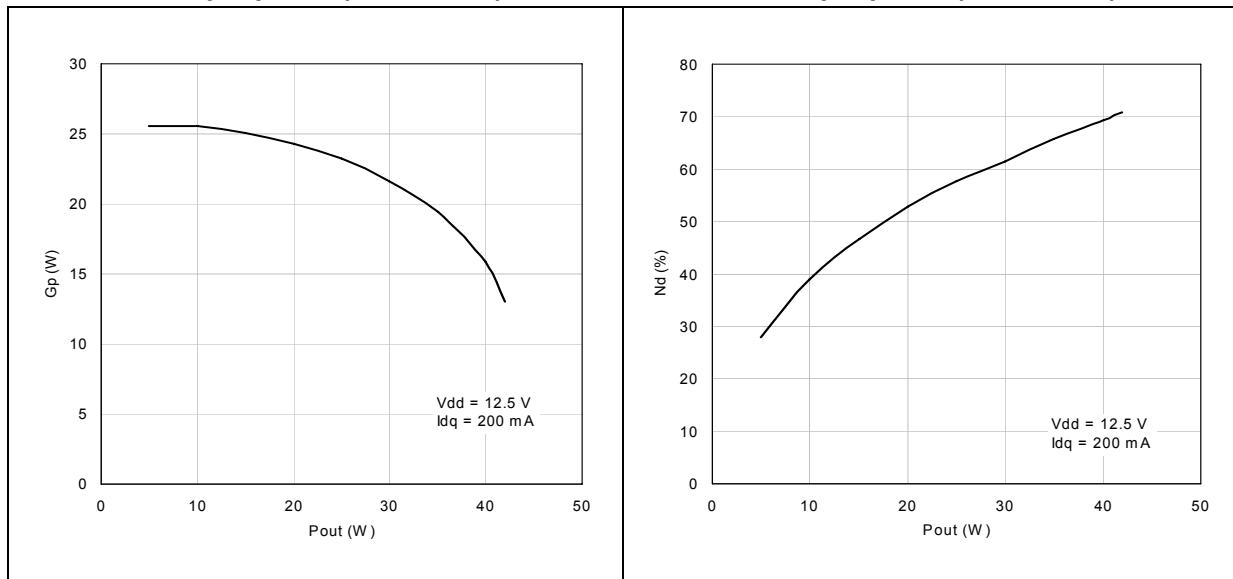
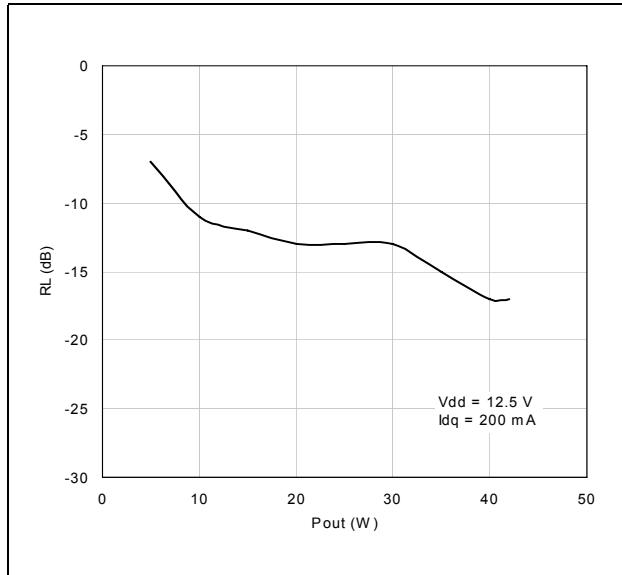
Figure 11. Output power vs bias current**Figure 12. Drain efficiency vs bias current****Figure 13. Output power vs supply voltage****Figure 14. Drain efficiency vs supply voltage**

Figure 15. Output power vs gate bias voltage**Figure 16.** Output power vs input power ($f = 175$ MHz)**Figure 17.** Power gain vs output power ($f = 175$ MHz)**Figure 18.** Drain efficiency vs output power ($f = 175$ MHz)

**Figure 19. Input return loss vs output power
($f = 175$ MHz)**



6 Circuit layout

Figure 21. 500 MHz test circuit

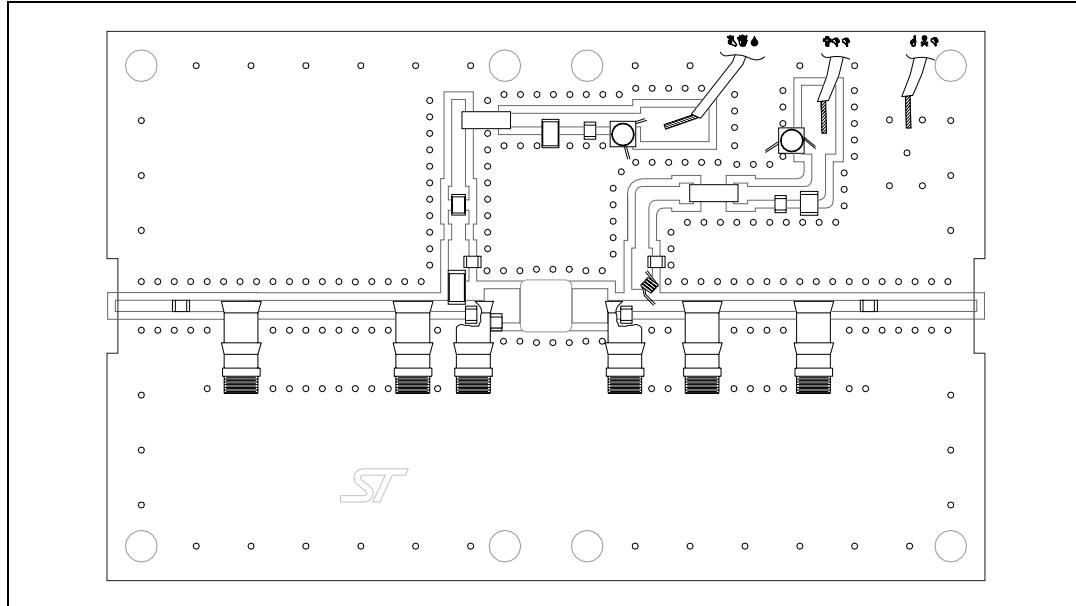


Figure 22. 500 MHz test circuit photomaster

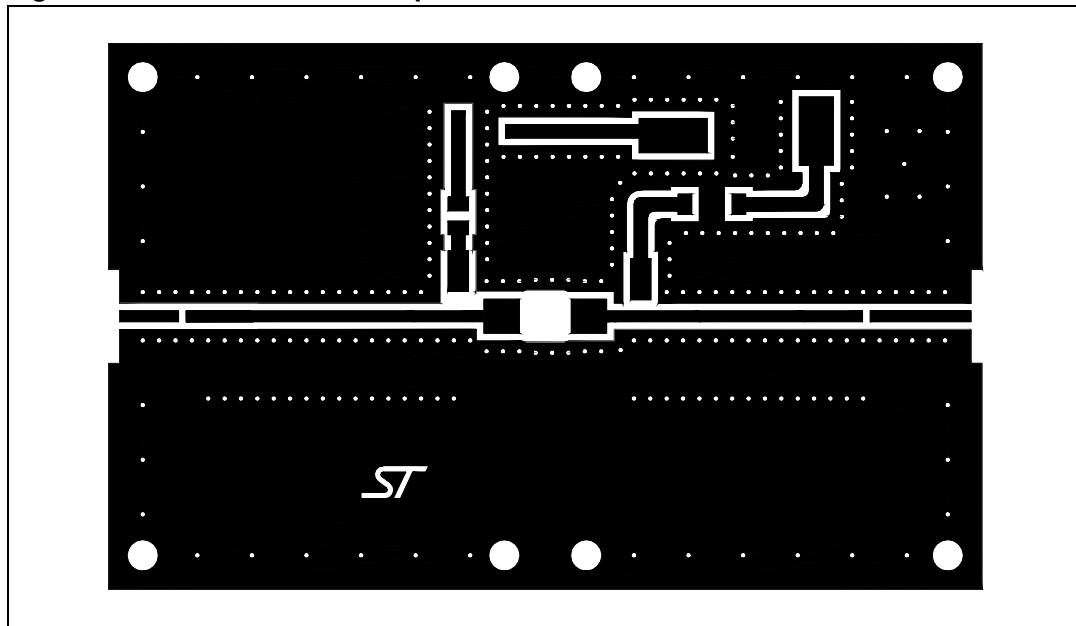
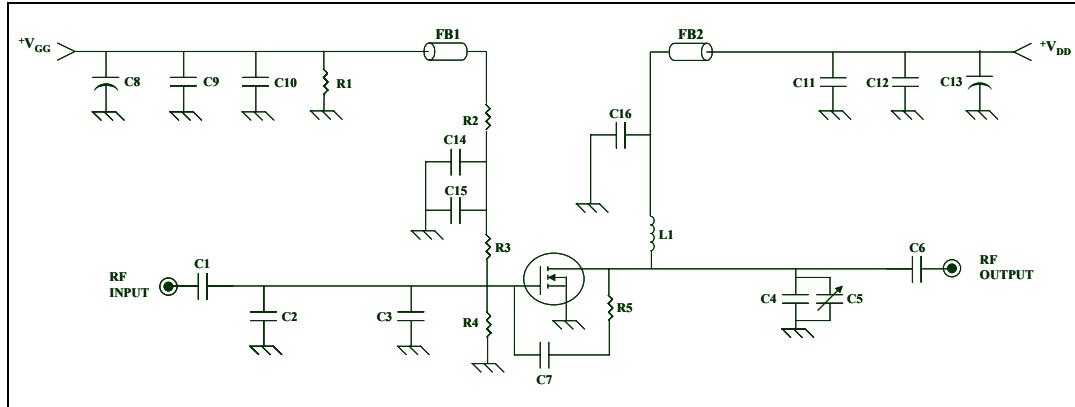


Figure 23. 175 MHz test circuit schematic (engineering)**Table 9.** 175 MHz test circuit component part list

Component	Description
C1, C6	300 pF chip capacitor
C2, C3	91 pF chip capacitor
C4, C14	75 pF chip capacitor
C5	1-20 pF trimmer capacitor
C7	.01 µF molded capacitor
C8, C13	10 µF electrolytic capacitor
C9, C12	.1 µF chip capacitor
C10, C11	1000 pF chip capacitor
C15, C16	1200 pF chip capacitor
FB1, FB2	Ferrite bead
R1	33 kΩ chip resistor
R2	17 Ω chip resistor
R3	15 Ω chip resistor
R4	47 Ω chip resistor
R5	220 Ω chip resistor
L1	5 turn, 16 AWG magnet wire, ID = .40", inductor
Board	Roger, ultra lam 2000, THK 0.030", $\epsilon_r = 2.55$ 2oz. ED cu 2 SIDES.

8 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com.
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Figure 26. Tube information

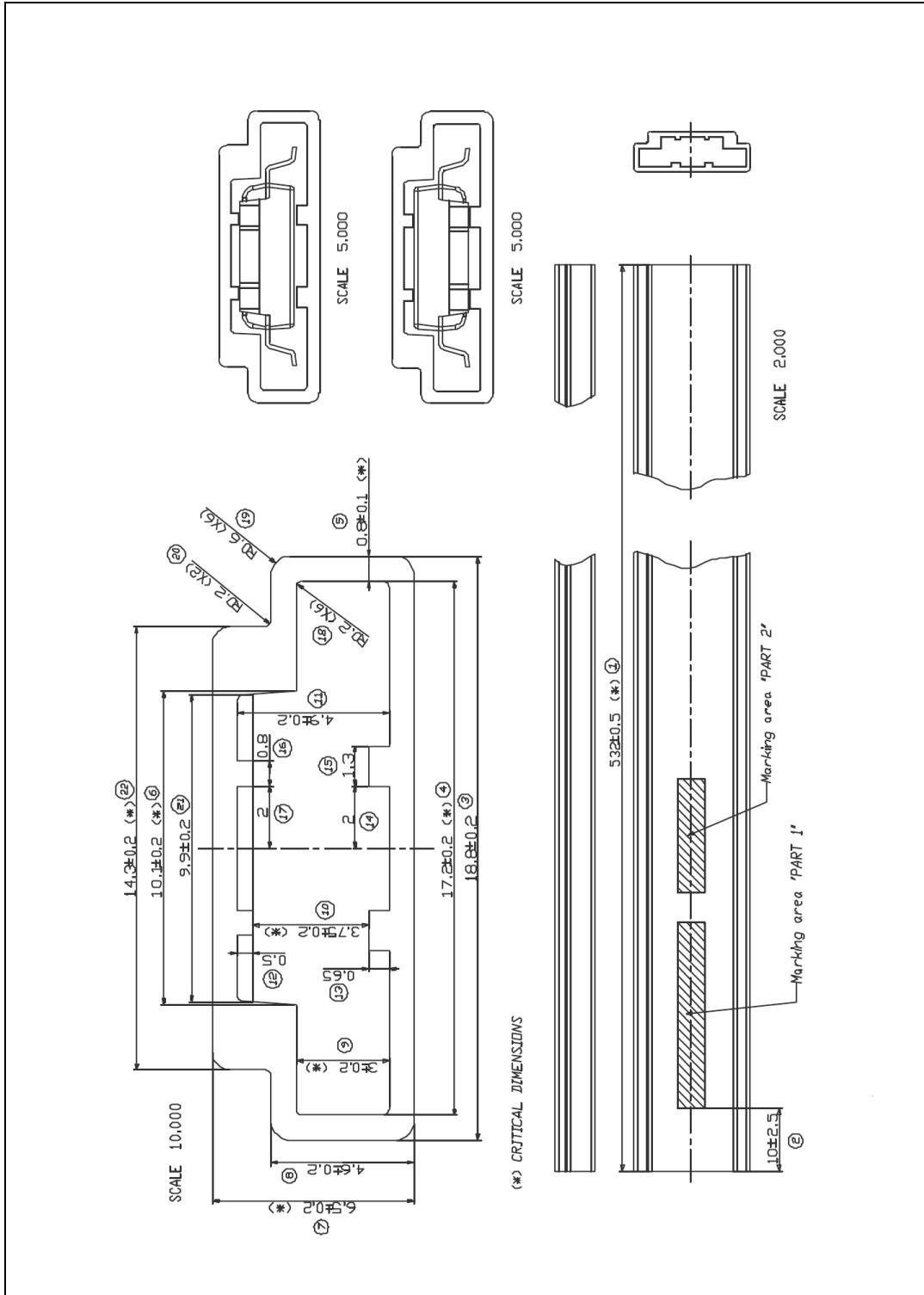
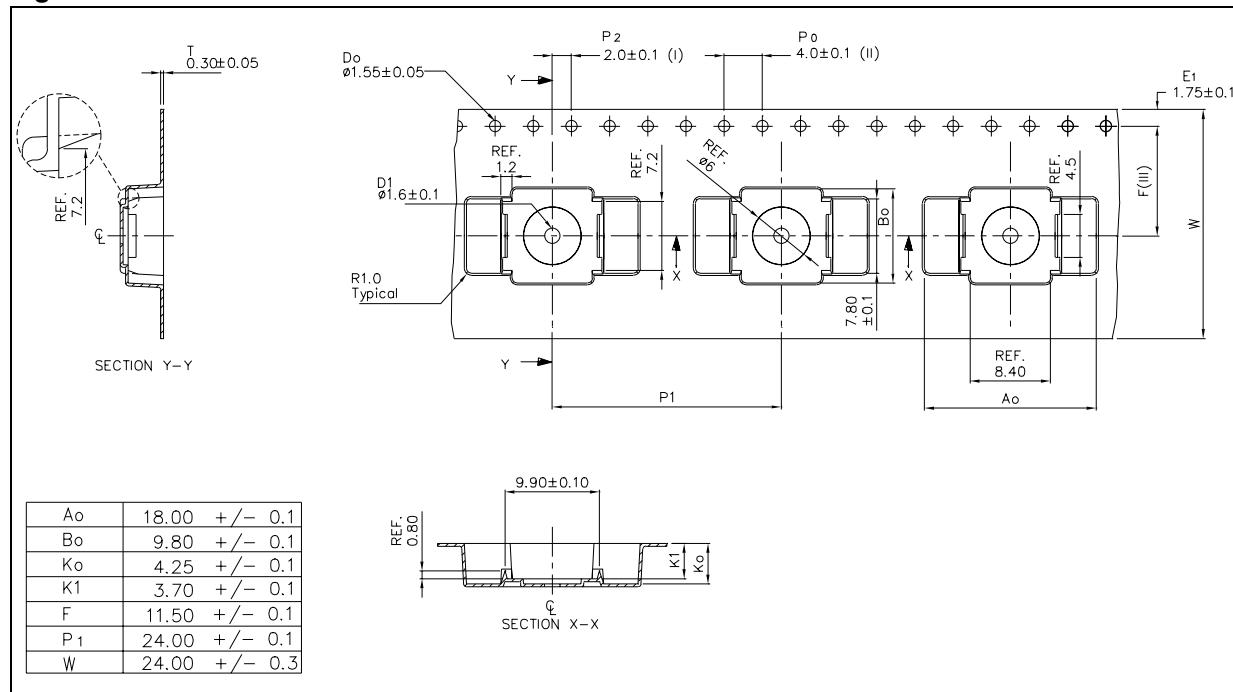


Figure 27. Reel information

9 Revision history

Table 16. Document revision history

Date	Revision	Changes
29-Apr-2006	1	Initial release.
03-Jun-2010	2	Added: Table 6: Moisture sensitivity level .

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